



承 认 书

SPECIFICATION FOR APPROVAL

客户名称:

CUSTOMER

产品名称:

PARTANME

红外接收管

规格料号:

PART NO

HPT-3215C-PB-TRZ

客户签章			鸿利泰签章		
DESIGNER	CHECKER	APPROVER	DESIGNER	CHECKER	APPROVER
			黄柏嫦	黄凯	马祥利

鸿利泰光电科技有限公司

HONGLITAI PHOTOELECTRICITY CO.,LTD

深圳市宝安沙井街道芙蓉工业区芙蓉 6 路 122 号

Tel:0755-29504006

Fax: 0755-29504016

<http://www.hlt-opto.com>

● Features:

1. Wide range of collector current
2. High photo sensitivity
3. Small junction capacitance
4. Pb free
5. lens color: water clear
6. The product itself will remain within RoHS compliant version

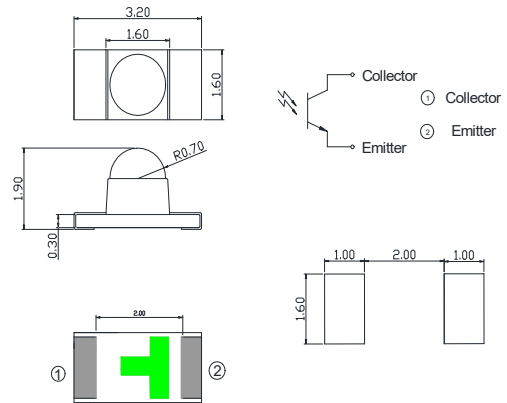
● Descriptions

1. The device is a phototransistor in miniature SMD package which is flat top view lens
2. The device is Spectrally matched to visible and infrared emitting diode

● Applications:

1. PCB mounted infrared sensor
2. Optoelectronic switch
3. Smoke detector
4. Intelligent water meter
5. Infrared keyboard
6. Infrared applied system

● Package Dimensions:



NOTES:

1. All dimensions are in millimeters (inches).
2. Tolerance is $\pm 0.25\text{mm}$ (0.01") unless otherwise specified.
3. Lead spacing is measured where the leads emerge from the package.
4. Specifications are subject to change without notice.

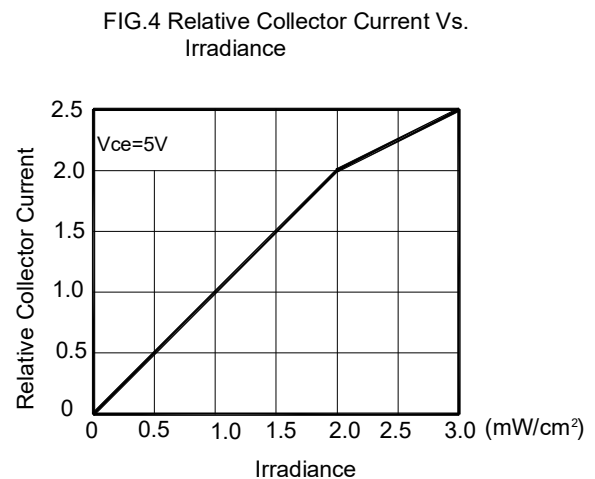
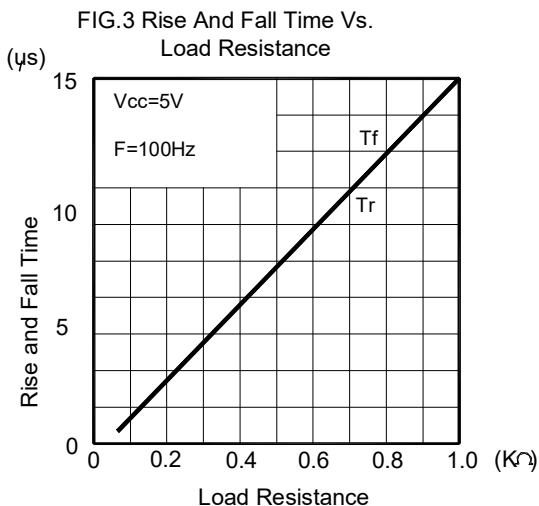
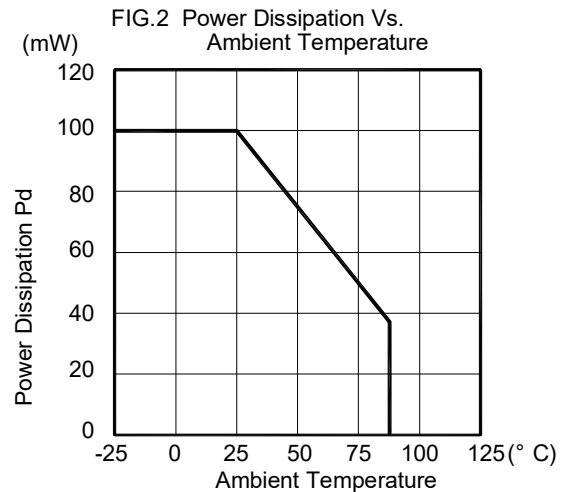
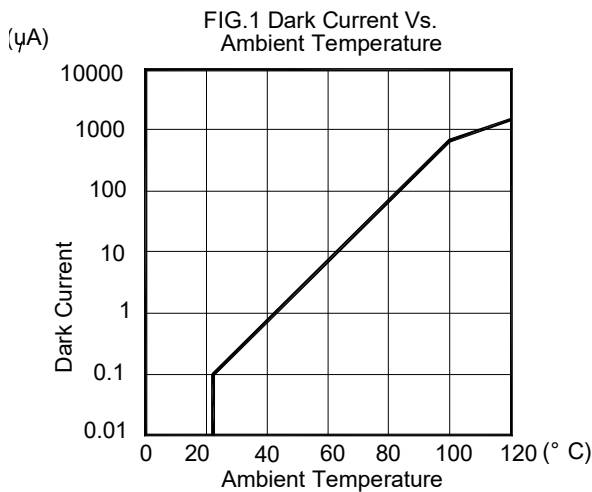
● Absolute Maximum Ratings(Ta=25°C)

Parameter	Maximum Rating	Unit
Power Dissipation	75	mW
Collector- Emitter Voltage	30	V
Emitter- Collector Voltage	5	V
Operating Temperature	-45°C~+85°C	
Storage Temperature Range	-45°C~+100°C	
Lead Soldering Temperature	260°C for 5 seconds	

● Optical- Electrical Characteristics (@TA=25°C)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Rang Of Spectral Bandwidth	$\lambda_{0.1}$	400		1100	nm	
Wavelength Of Peak Sensitiv	λ_p	-	940	-		
Collector- Emitter Breakdown Voltage	$V_{(BR)CEO}$	30	-	-	V	$I_C=100 \mu A$ $E_e=0mW/cm^2$
Emitter-Collector Breakdown Voltage	$V_{(BR)ECO}$	5	-	-	V	$I_E=100 \mu A$ $E_e=0mW/cm^2$
Collector- Emitter Saturation Voltage	$V_{CE(SAT)}$	-	-	0.5	V	$I_C=2mA$ $I_B=100 \mu A$
Rise Time	T_r	-	15	-	μS	$V_{CC}=5V$ $R_L=1K\Omega$ $I_C=1mA$
Fall Time	T_f	-	15	-	μS	$V_{CC}=5V$ $R_L=1K\Omega$ $I_C=1mA$
Collector Dark Current	I_{CEO}	-	-	100	nA	$V_{CE}=20V$ $E_e=0mW/cm^2$
On State Collector Current	$I_{C(ON)}$	-	5	-	mA	$V_{CE}=5V$ $E_e=1.0mW/cm^2$

● Typical Optical-Electrical Characteristic Curves

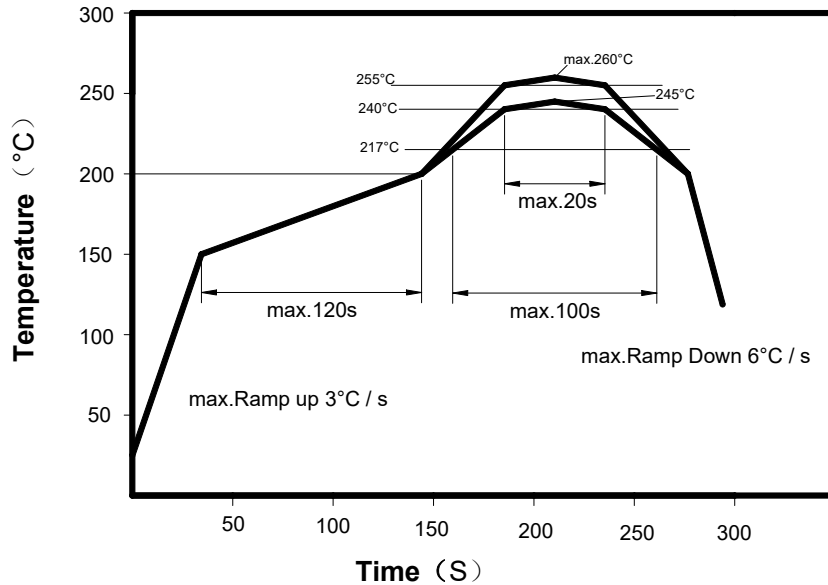


● Soldering Condition:

Preheating : 120°C, Within 120°C ~ 180°C sec.

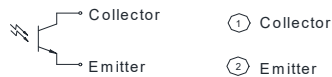
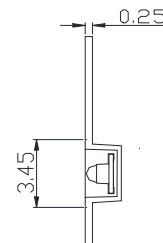
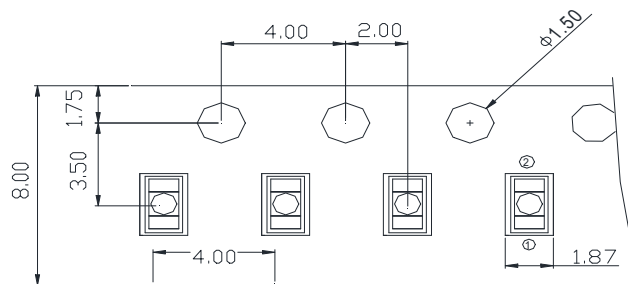
Operation heating : 255°C ± 5°C Within 5 sec. 260°C (Max)

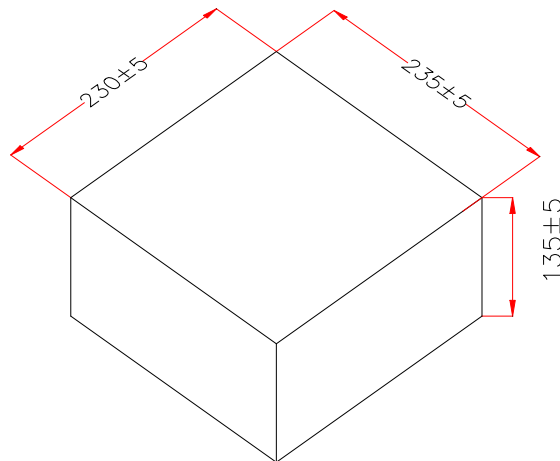
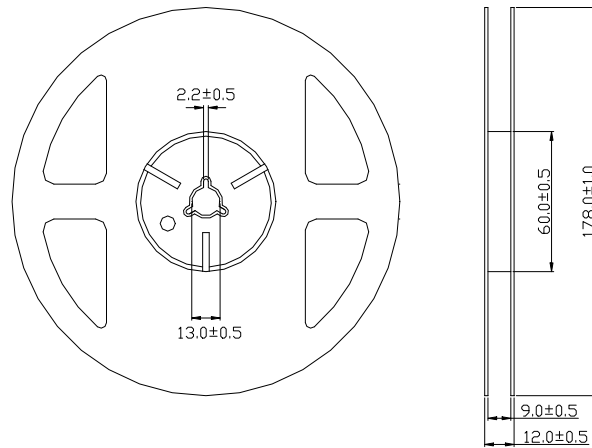
Gradual Cooling (Avoid quenching).



1. Reflow soldering should not be done more than two times.
2. When soldering, do not put stress on the LEDs during heating.
3. After soldering, do not warp the circuit board.

● Package Bag Dimensions





NOTES:

1. 4000 PCS per reel, 12 reels per Carton.
2. All dimensions are in millimeters (inches).
3. Tolerance is $\pm 0.30\text{mm}$ (0.012") unless otherwise specified.
4. Specifications are subject to change without notice.